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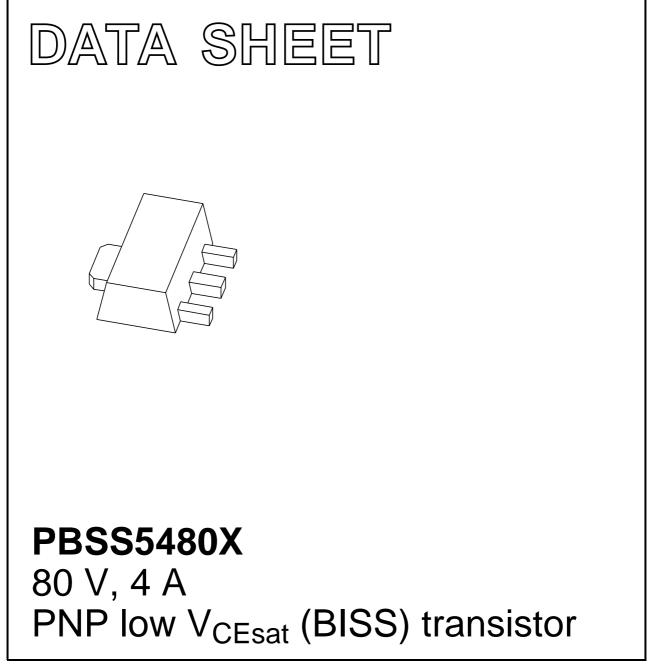
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DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2004 Jun 8 2004 Nov 08



80 V, 4 A PNP low V_{CEsat} (BISS) transistor

FEATURES

- High h_{FE} and low V_{CEsat} at high current operation
- High collector current I_C: 4 A
- High efficiency leading to less heat generation.

APPLICATIONS

- Medium power peripheral drivers (e.g. fans and motors)
- Strobe flash units for digital still cameras and mobile phones
- Inverter applications (e.g. TFT displays)
- Power switch for LAN and ADSL systems
- Medium power DC-to-DC conversion
- Battery chargers.

DESCRIPTION

PNP low V_{CEsat} (BISS) transistor in a SOT89 (SC-62) plastic package. NPN complement: PBSS4480X.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾
PBSS5480X	*1Z

Note

- 1. * = p: made in Hong Kong.
 - * = t: made in Malaysia.
 - * = W: made in China.

ORDERING INFORMATION

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT	
V _{CEO}	collector-emitter voltage	-80	V	
I _C	collector current (DC)	-4	А	
I _{CM}	peak collector current	-10	А	
R _{CEsat}	equivalent on-resistance	75	mΩ	

PINNING

PIN	DESCRIPTION	
1	emitter	
2	collector	
3	base	

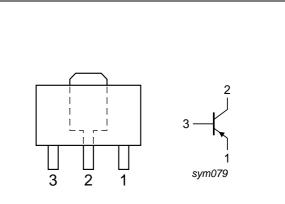


Fig.1 Simplified outline (SOT89) and symbol.

TYPE NUMBER		PACKAGE		
	NAME	DESCRIPTION	VERSION	
PBSS5480X	SC-62	-62 plastic surface mounted package; collector pad for S good heat transfer; 3 leads		

PBSS5480X

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

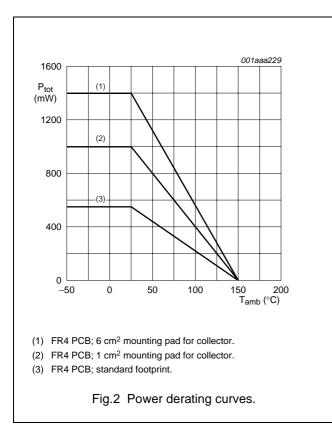
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	-80	V
V _{CEO}	collector-emitter voltage	open base	-	-80	V
V _{EBO}	emitter-base voltage	open collector	-	-5	V
I _C	collector current (DC)	note 1	-	-4	А
I _{CM}	peak collector current	$t_p \le 1$ ms or limited by $T_{j(max)}$	-	-10	А
I _{CRP}	repetitive peak collector current	$t_p \le 10 \text{ ms}; \delta \le 0.1$	-	-6	А
I _B	base current (DC)		-	-1	А
I _{BM}	peak base current	$t_p \le 1 ms$	-	-2	А
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
		notes 2 and 3	_	2.5	W
		note 3	_	0.55	W
		note 4	_	1	W
		note 1	_	1.4	W
		note 5	_	1.6	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

Notes

1. Device mounted on a printed-circuit board, single-sided copper, tin-plated, mounting pad for collector 6 cm².

2. Operated under pulsed conditions; pulse width $t_p \leq$ 10 ms; duty cycle $\delta \leq$ 0.1.

- 3. Device mounted on a printed-circuit board, single-sided copper, tin-plated, standard footprint.
- 4. Device mounted on a printed-circuit board, single-sided copper, tin-plated, mounting pad for collector 1 cm².
- 5. Device mounted on a 7 cm² ceramic printed-circuit board, 1 cm² single-sided copper, tin-plated.



PBSS5480X

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air		
		notes 1 and 2	50	K/W
		note 2	225	K/W
		note 3	125	K/W
		note 4	90	K/W
		note 5	80	K/W
R _{th(j-s)}	thermal resistance from junction to soldering point		16	K/W

Notes

- 1. Operated under pulsed conditions; pulse width $t_p \leq$ 10 ms; duty cycle $\delta \leq$ 0.2.
- 2. Device mounted on a printed-circuit board, single-sided copper, tin-plated, standard footprint.
- 3. Device mounted on a printed-circuit board, single-sided copper, tin-plated, mounting pad for collector 1 cm².
- 4. Device mounted on a printed-circuit board, single-sided copper, tin-plated, mounting pad for collector 6 cm².
- 5. Device mounted on a 7 cm² ceramic printed-circuit board, 1 cm² single-sided copper, tin-plated.

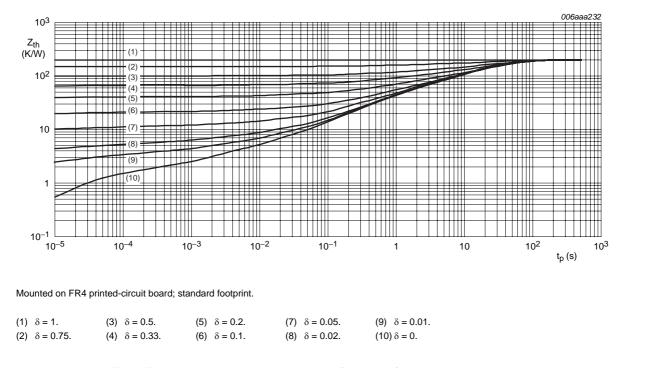
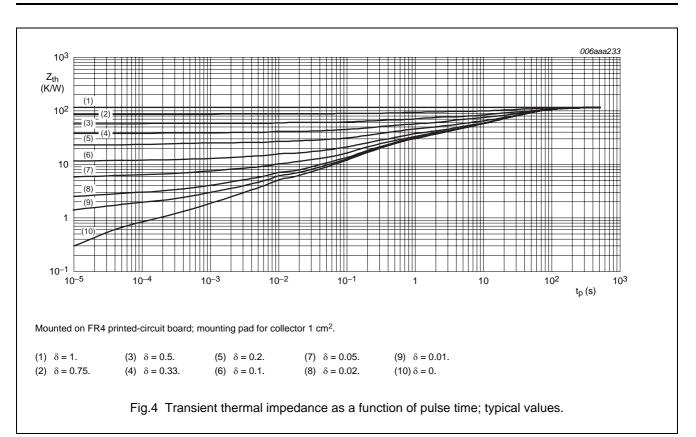
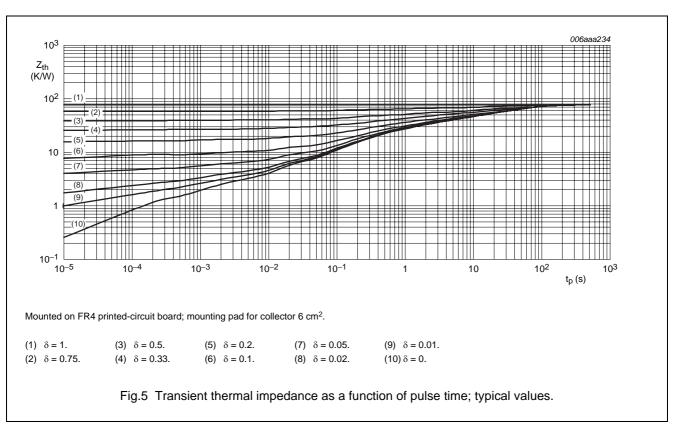


Fig.3 Transient thermal impedance as a function of pulse time; typical values.





PBSS5480X

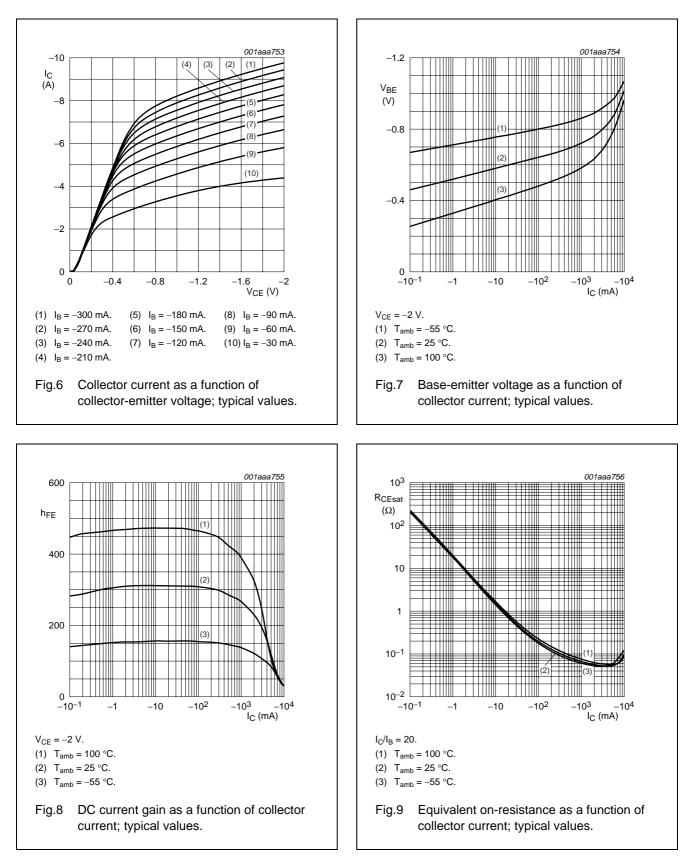
CHARACTERISTICS

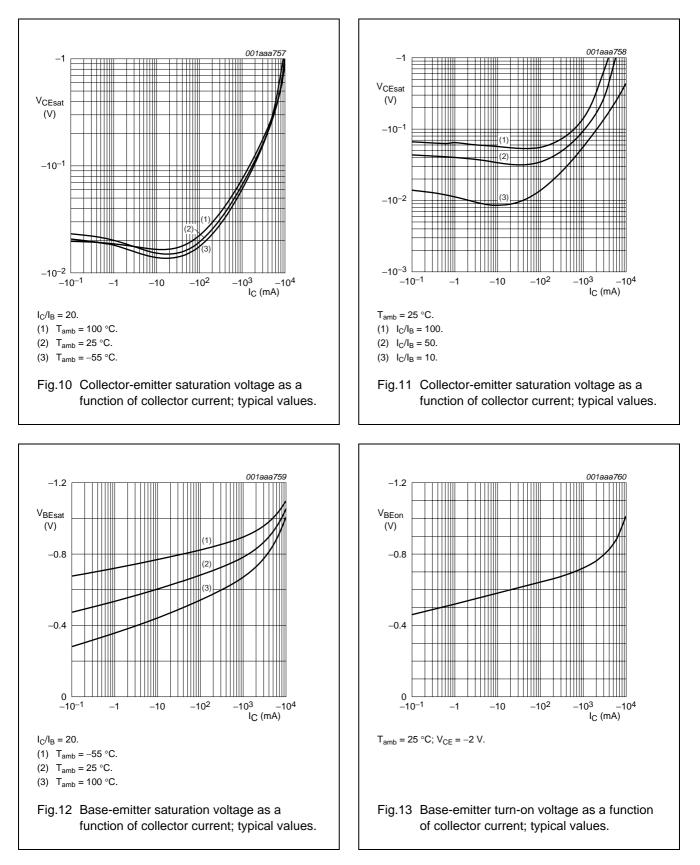
 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -80 \text{ V}; I_E = 0 \text{ A}$	-	_	-100	nA
		$V_{CB} = -80 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$	-	_	-50	μA
I _{CES}	collector-emitter cut-off current	$V_{CE} = -60 \text{ V}; \text{ V}_{BE} = 0 \text{ V}$	-	-	-100	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	-100	nA
h _{FE}	DC current gain	$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -0.5 \text{ A}$	200	300	-	
		$V_{CE} = -2 V; I_{C} = -1 A;$ note 1	180	280	-	
		$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -2 \text{ A}; \text{ note } 1$	150	240	-	
		$V_{CE} = -2$ V; $I_{C} = -4$ A; note 1	80	150	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C} = -0.5 \text{ A}; I_{\rm B} = -50 \text{ mA}$	_	-35	-55	mV
		$I_{\rm C} = -1$ A; $I_{\rm B} = -50$ mA	_	-70	-105	mV
		$I_{\rm C} = -2$ A; $I_{\rm B} = -40$ mA	_	-170	-250	mV
		$I_{C} = -4 \text{ A}; I_{B} = -200 \text{ mA}; \text{ note } 1$	_	-220	-340	mV
		$I_{C} = -5 \text{ A}; I_{B} = -500 \text{ mA}; \text{ note } 1$	_	-250	-380	mV
R _{CEsat}	equivalent on-resistance	$I_{C} = -5 \text{ A}; I_{B} = -500 \text{ mA}; \text{ note } 1$	_	50	75	mΩ
V _{BEsat}	base-emitter saturation voltage	$I_{\rm C} = -0.5 \text{ A}; I_{\rm B} = -50 \text{ mA}$	_	-770	-850	mV
		$I_{\rm C} = -1$ A; $I_{\rm B} = -50$ mA	_	-810	-900	mV
		$I_{C} = -1 \text{ A}; I_{B} = -100 \text{ mA}; \text{ note } 1$	_	-810	-900	mV
		$I_{C} = -4 \text{ A}; I_{B} = -400 \text{ mA}; \text{ note } 1$	_	-930	-1000	mV
V _{BEon}	base-emitter turn-on voltage	$V_{CE} = -2 \text{ V}; \text{ I}_{C} = -2 \text{ A}$	-	-760	-850	mV
f _T	transition frequency	$I_{C} = -0.1 \text{ A}; V_{CE} = -10 \text{ V};$ f = 100 MHz	100	125	-	MHz
C _c	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = -10 \text{ V}; \text{ I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} = 1 \text{ MHz} \end{array}$	_	60	90	pF

Note

1. Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$

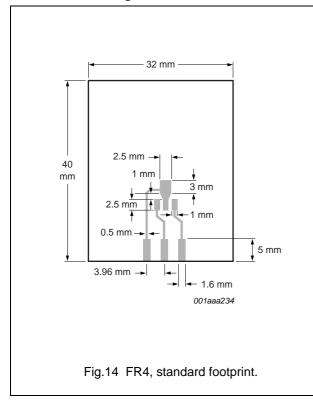


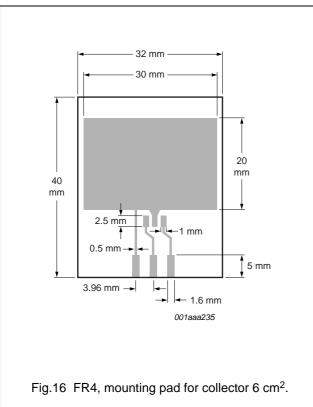


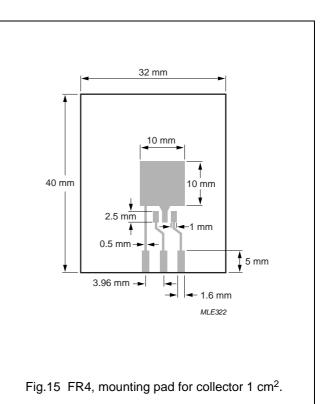
PBSS5480X

80 V, 4 A PNP low V_{CEsat} (BISS) transistor

Reference mounting conditions

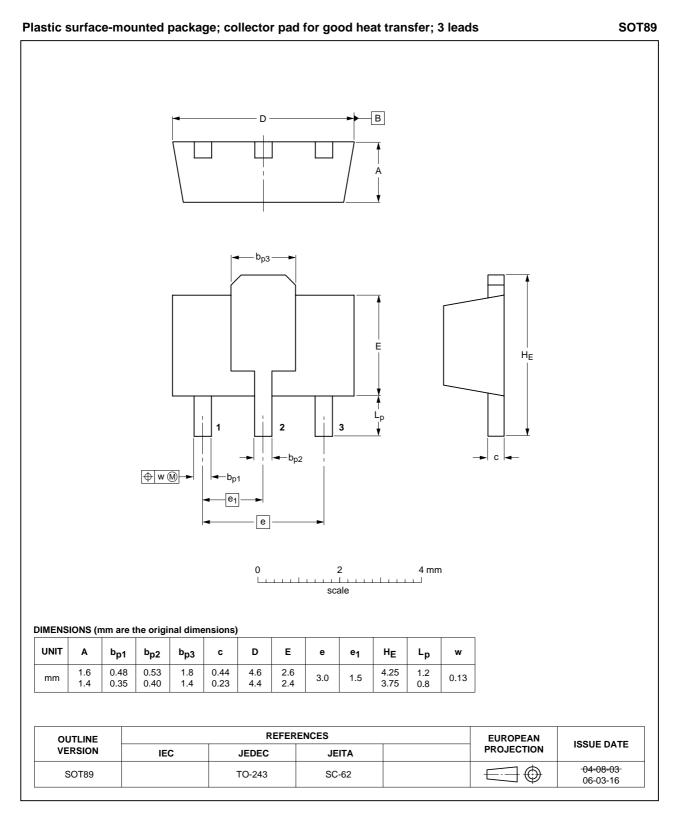






2004 Nov 08

PACKAGE OUTLINE



PBSS5480X

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION	
Objective data sheet	Development	This document contains data from the objective specification for product development.	
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.	
Product data sheet	Production	This document contains the product specification.	

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Contact information

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